National Semiconductor Corporation

# LM2879 Dual 8-Watt Audio Amplifier

# **General Description**

The LM2879 is a monolithic dual power amplifier which offers high quality performance for stereo phonographs, tape players, recorders, AM-FM stereo receivers, etc.

The LM2879 will deliver 8W/channel to an  $8\Omega$  load. The amplifier is designed to operate with a minimum of external components and contains an internal bias regulator to bias each amplifier. Device overload protection consists of both internal current limit and thermal shutdown.

#### Features

- A<sub>VO</sub> typical 90 dB
- 9W per channel (typical)
- 60 dB ripple rejection
- 70 dB channel separation

- Self-centering biasing
- 4 MΩ input impedance
- Internal current limiting
- Internal thermal protection

### Applications

- Multi-channel audio systems
- Tape recorders and players
- Movie projectors
- Automotive systems
- Stereo phonographs
- Bridge output stages
- AM-FM radio receivers
- Intercoms
- Servo amplifiers
- Instrument systems

# **Connection Diagram and Typical Application**



TL/H/5291-1

Order Number LM2879T See NS Package Number T11A



#### **Absolute Maximum Ratings**

Input Voltage (Note 1)

**Operating Temperature (Note 2)** 

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/ Distributors for availability and specifications. Supply Voltage 35V

Storage Temperature	-65°C to +150°C
Junction Temperature	150°C
Lead Temp. (Soldering, 10 seconds)	260°C
ESD rating to be determined.	

<b>Electrical Characteristics</b> v	28V, $T_{TAB} = 25^{\circ}$ C, $R_{L} = 8\Omega$ , $A_{V} = 50$ (34 dB), unless otherwise specified.
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±0.7V

0°C to + 70°C

Parameter	Conditions	Min	Тур	Max	Units
Total Supply Current	P <sub>O</sub> =0W		12	65	mA
Operating Supply Voltage		6		32	V
Output Power/Channel	f=1 kHz, THD=10%, T <sub>TAB</sub> =25°C	6	8		w
Distortion	$f = 1 \text{ kHz}, R_L = 8\Omega$ $P_O = 1 \text{ W/Channel}$		0.05	1	%
Output Swing	R <sub>L</sub> =8Ω		V <sub>S</sub> -6V		Vp-р
Channel Separation	$\begin{array}{l} C_{BYPASS}\!=\!50\;\mu\text{F}, C_{IN}\!=\!0.1\;\mu\text{F}\\ \text{f}\!=\!1\;\text{kHz}, \text{Output Referred}\\ V_O\!=\!4\;\text{Vrms} \end{array}$	- 50	-70		dB
PSRR Positive Supply	C <sub>BYPASS</sub> =50 μF, C <sub>IN</sub> =0.1 μF f=120 Hz, Output Referred V <sub>ripple</sub> =1 Vrms	-50	-60		dB
PSRR Negative Supply	Measured at DC, Input Referred		-60		dB
Common-Mode Range	Split Supplies ±15V, Pin 1 Tied to Pin 11		±13.5		v
Input Offset Voltage			10		mV
Noise	Equivalent Input Noise $R_S=0, C_{IN}=0.1 \ \mu F$ $BW=20-20 \ KHz$ CCIR•ARM Output Noise Wideband $R_S=0, C_{IN}=0.1 \ \mu F, A_V=200$		2.5 3.0 0.8		μV μV mV
Open Loop Gain	$R_{S}=51\Omega$ , f=1 kHz, $R_{L}=8\Omega$		70		dB
Input Bias Current			100		nA
Input Impedance	Open Loop		4		MΩ
DC Output Voltage	V <sub>S</sub> =28V		14		V
Slew Rate			2		V/μs
Power Bandwidth	3 dB Bandwidth at 2.5W		65		kHz
Current Limit			1.5		A

Note 1: The input voltage range is normally limited to ±0.7V with respect to pin 1. This range may be extended by shorting pin 1 to the positive supply. Note 2: For operation at ambient temperature greater than 25°C, the LM2879 must be derated based on a maximum 150°C junction temperature. Thermal resistance, junction to case, is 3°C/W. Thermal resistance, case to ambient, is 40°C/W.

# **Typical Performance Characteristics**





#### **Power Dissipation vs Power Output**





LM2879





## Typical Applications (Continued)





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